

BC807-40W-QX Datasheet



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DiGi Electronics Part Number BC807-40W-QX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC807-40W-QX

Description TRANS PNP 45V 0.5A SOT323

Detailed Description Bipolar (BJT) Transistor PNP 45 V 500 mA 80MHz 20

0 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC807-40W-QX	Nexperia USA Inc.
Series:	Product Status:
BC807W-Q	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	250 @ 100mA, 1V
Power - Max:	Frequency - Transition:
200 mW	80MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
SC-70, SOT-323	SOT-323
Base Product Number:	
BC807	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



45 V, 500 mA PNP general-purpose transistors

Rev. 1 — 8 June 2021

Product data sheet

1. General description

PNP general-purpose transistors in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	NPN complement		
	Nexperia	JEDEC	JEITA	
BC807W-Q	SOT323	-	SC-70	BC817W-Q
BC807-16W-Q				BC817-16W-Q
BC807-25W-Q				BC817-25W-Q
BC807-40W-Q				BC817-40W-Q

2. Features and benefits

- High current
- Three current gain selections
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	-45	V
I _C	collector current	T _{amb} = 25 °C		-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	-1	Α
h _{FE}	DC current gain			•			
	BC807W-Q	V_{CE} = -1 V; I_{C} = -100 mA T_{amb} = 25 °C	[1]	100	-	600	
	BC807-16W-Q		[1]	100	-	250	
	BC807-25W-Q		[1]	160	-	400	
	BC807-40W-Q		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	Е	emitter		В
3	С	collector		, h
				E sym132
				J,2
			1 🗀 🗀 2	

6. Ordering information

Table 4. Ordering information

Type number	umber Package			
	Name	Description	Version	
BC807W-Q	SC-70	Plastic surface-mounted package; 3 leads	SOT323	
BC807-16W-Q				
BC807-25W-Q				
BC807-40W-Q				

7. Marking

Table 5. Marking

Type number	Marking code[1]			
BC807W-Q	5D%			
BC807-16W-Q	5A%			
BC807-25W-Q	5B%			
BC807-40W-Q	5C%			

[1] % = placeholder for manufacturing site code

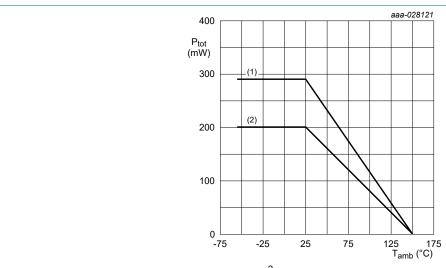
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C			V
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	-5	V
I _C	collector current	T _{amb} = 25 °C		-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °	С	-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	200	mW
			[3] [2]	-	290	mW
Tj	junction temperature					°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB; single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

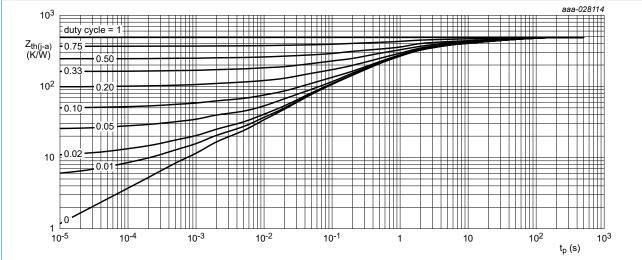
Fig. 1. Power derating curves

9. Thermal characteristics

Table 7. Thermal characteristics

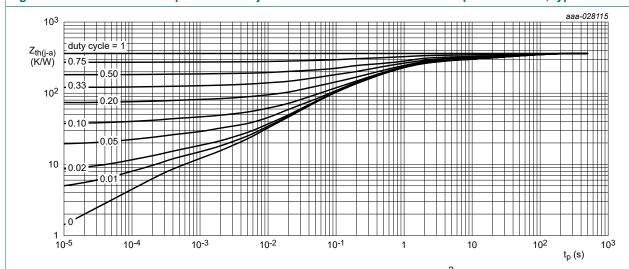
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	625	K/W
			[3] [2]	-	-	431	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB; single-sided copper, tin-plated; mounting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

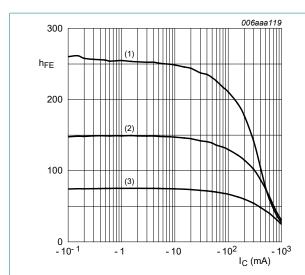
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_{C} = -10 \text{ mA}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-45	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = -100 \ \mu A; I_C = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-5	-	-	V
I _{CBO}	collector-base	V _{CB} = -20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	cut-off current	V _{CB} = -20 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain				'	'	
BC807W-Q BC807-16W-Q	BC807W-Q	V _{CE} = -1 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	100	-	600	
		[1]	100	-	250		
	BC807-25W-Q		[1]	160	-	400	
	BC807-40W-Q		[1]	250	-	600	
h _{FE}	DC current gain	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	-700	mV
V_{BE}	base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1] [2]	-	-	-1.2	V
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C		80	-	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	5	-	pF

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \ \mu\text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \ \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



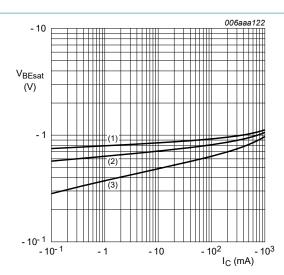
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$





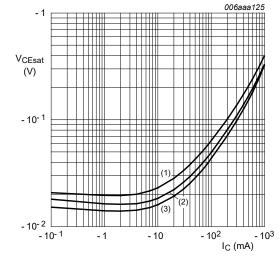
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC807-16W-Q: Base-emitter saturation voltage as a function of collector current; typical values



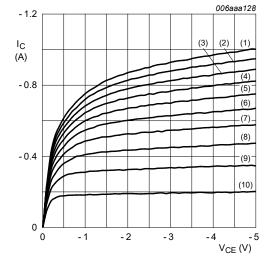
IC/IB = 10

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC807-16W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

(1) $I_B = -16.0 \text{ mA}$

(2) $I_B = -14.4 \text{ mA}$

(3) $I_B = -12.8 \text{ mA}$

 $(4) I_B = -11.2 \text{ mA}$

 $(5) I_B = -9.6 \text{ mA}$

(6) $I_B = -8.0 \text{ mA}$

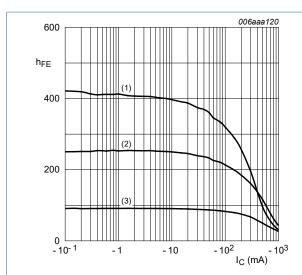
 $(7) I_B = -6.4 \text{ mA}$

 $(8) I_B = -4.8 \text{ mA}$

(9) $I_B = -3.2 \text{ mA}$

 $(10) I_B = -1.6 \text{ mA}$

Fig. 7. BC807-16W-Q: Collector current as a function of collector-emitter voltage; typical values



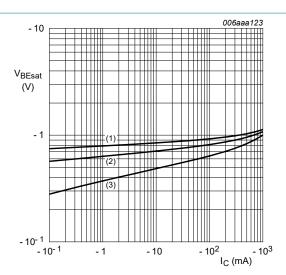
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC807-25W-Q: DC current gain as a function of collector current; typical values



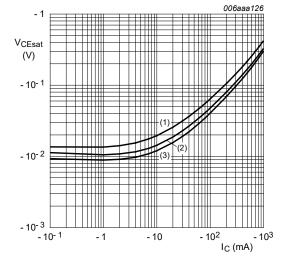
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC807-25W-Q: Base-emitter saturation voltage as a function of collector current; typical values

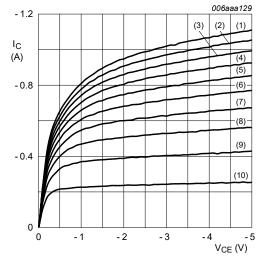


$$IC/IB = 10$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC807W-25-Q: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = -13.0 \text{ mA}$$

(2)
$$I_B = -11.7 \text{ mA}$$

(3)
$$I_B = -10.4 \text{ mA}$$

$$(4) I_B = -9.1 mA$$

$$(5) I_B = -7.8 \text{ mA}$$

(6)
$$I_B = -6.5 \text{ mA}$$

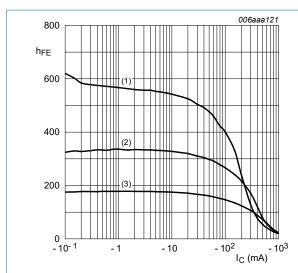
(7)
$$I_B = -5.2 \text{ mA}$$

(8)
$$I_B = -3.9 \text{ mA}$$

(9)
$$I_B = -2.6 \text{ mA}$$

$$(10) I_B = -1.3 \text{ mA}$$

Fig. 11. BC807W-25-Q: Collector current as a function of collector-emitter voltage; typical values



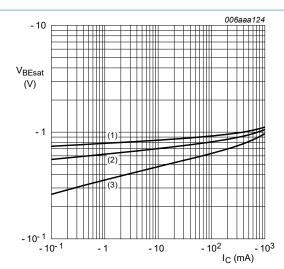
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

collector current; typical values

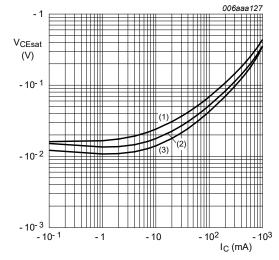


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 12. BC807-40W-Q: DC current gain as a function of Fig. 13. BC807-40W-Q: Base-emitter saturation voltage as a function of collector current; typical values

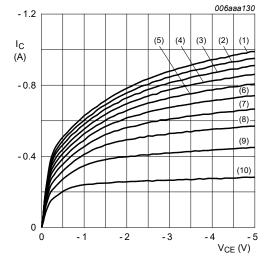


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 14. BC807-40W-Q: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = -12.0 \text{ mA}$

(2) $I_B = -10.8 \text{ mA}$

(3) $I_B = -9.6 \text{ mA}$

 $(4) I_B = -8.4 \text{ mA}$

 $(5) I_B = -7.2 \text{ mA}$

(6) $I_B = -6.0 \text{ mA}$

 $(7) I_B = -4.8 \text{ mA}$

(8) $I_B = -3.6 \text{ mA}$

(9) $I_B = -2.4 \text{ mA}$

 $(10) I_B = -1.2 mA$

Fig. 15. BC807-40W-Q: Collector current as a function of collector-emitter voltage; typical values

45 V, 500 mA PNP general-purpose transistors

11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

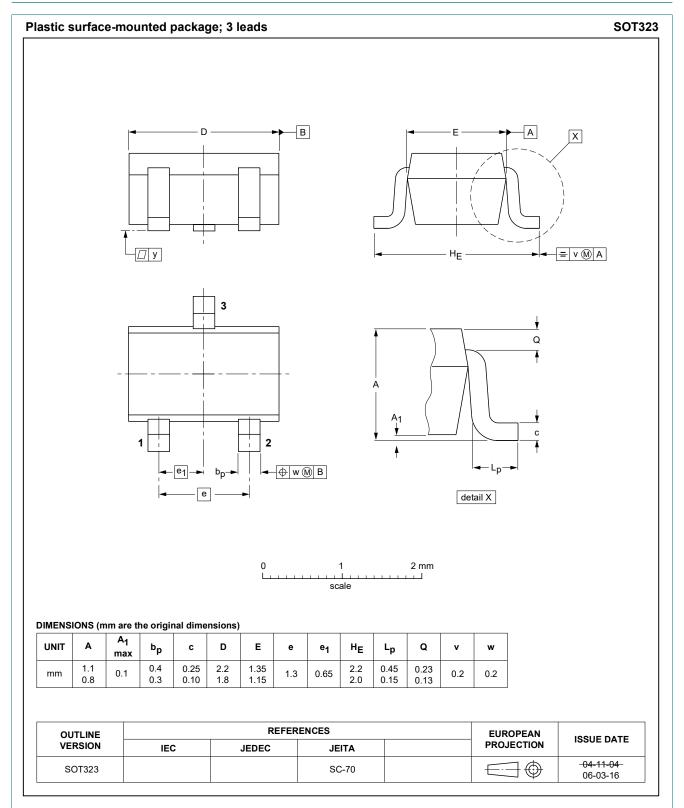
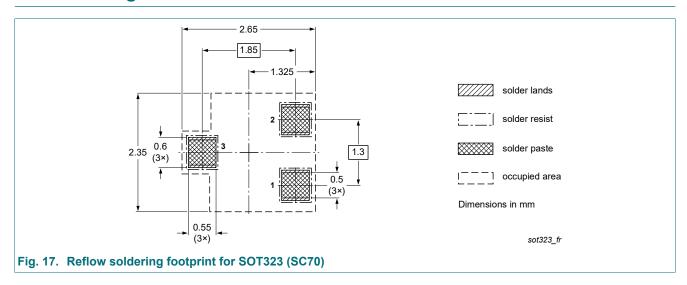
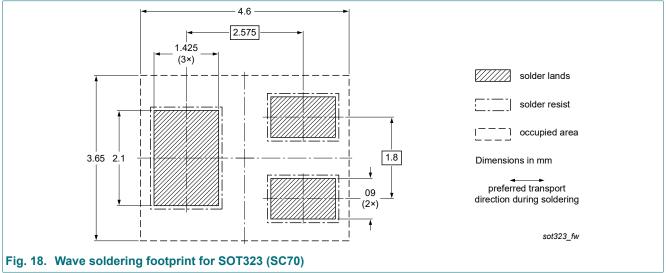


Fig. 16. Package outline SOT323 (SC-70)

13. Soldering





45 V, 500 mA PNP general-purpose transistors

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC807W-Q_SER v.1	20210608	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Nexperia

BC807W-Q series

45 V, 500 mA PNP general-purpose transistors

Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	Characteristics	5
11.	Test information	9
11.	1. Quality information	9
	Package outline1	
	Soldering1	
14.	Revision history1	2
	Legal information1	

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